Practitioner's Docket No.: 811 107 PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the application of: Makoto IWAI, Katsuhiro IMAI and Minoru IMAEDA

Ser. No.: 10/594,846 Group Art Unit: 1792

Filed: November 8, 2006 Examiner: Felisa Carla Hiteshew

Confirmation No.: 3664

For: GALLIUM NITRIDE SINGLE CRYSTAL GROWING METHOD AND

GALLIUM NITRIDE SINGLE CRYSTAL

Mail Stop Amendment Commissioner for Patents P.O. Box 1450

Alexandria, VA 22313-1450

EFS CERTIFICATE OF TRANSMISSION

I hereby certify that this paper is being transmitted via EFS to the Patent and Trademark Office on *October 22, 2008*.

Janet M. Stevens

AMENDMENT

Sir:

In response to the Office Action mailed September 19, 2008, please amend the aboveidentified application as follows:

Amendments to the Claims are reflected in the listing of claims which begins on page 2 of this paper.

Remarks/Arguments begin on page 4 of this paper.